

Features

 High current surface mount P P silicon switching transistor for Load management in portable applications

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
PBSS5120T,215	SOT-23	589	3000

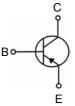


1. BASE

2. EMITTER

3. COLLECTOR

SOT-23



Maximum Ratings (Ta=25 unless otherwise noted)

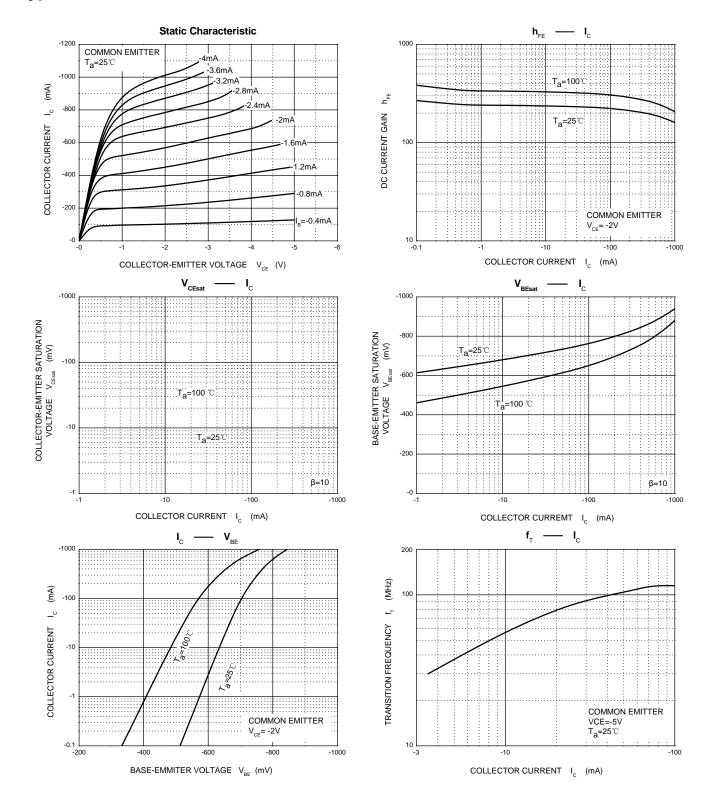
Symbol	Parameter	Value	Unit
V _{СВО}	Collector-Base Voltage	-50	V
V _{CEO}	Collector-Emitter Voltage	-30	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current	-1	Α
Pc	Collector Power Dissipation	310	mW
R _{OJA}	Thermal Resistance From Junction To Ambient	403	°C/W
T_J, T_stg	Operation Junction and Storage Temperature Range	-55~+150	℃

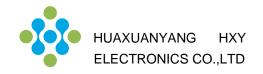
Electrical Characteristics (Ta=25 unless otherwise specified)

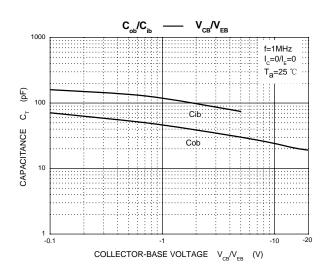
Parameter	Symbol	Test conditions	Min	Max	Unit
Collector-base breakdown voltage	V _{(BR)CBO}	I _C =-100μΑ,I _E =0	-50		V
Collector-emitter breakdown voltage	V _{(BR)CEO}	I _C =-10mA,I _B =0	-30		V
Emitter-base breakdown voltage	V _{(BR)EBO}	I _E =-100μA,I _C =0	-5		V
Collector cut-off current	I _{CBO}	V _{CB} =-30V,I _E =0		-0.1	μΑ
Collector-emitter cut-off current	I _{CES}	V _{CES} =-30V		-0.1	μΑ
Emitter cut-off current	I _{EBO}	V _{EB} =-4V,I _C =0		-0.1	μΑ
DC current gain	h _{FE1}	V _{CE} =-2V,I _C =-1mA	100		
	h _{FE2}	V _{CE} =-2V,I _C =-500mA	100	300	
	h _{FE3}	V _{CE} =-2V,I _C =-1A	80		
	h _{FE4}	V _{CE} =-2V,I _C =-2A	40		
	V _{CE(sat)1}	I _C = -500mA, I _B =-50mA		-0.25	V
Collector-emitter saturation voltage	V _{CE(sat)2}	I _C = -1A, I _B =-100mA		-0.3	V
	V _{CE(sat)3}	I _C = -2A, I _B =-200mA		-0.65	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = -1A, I _B =-100mA		-1.2	V
Base-emitter Turn-on voltage	V _{BE(on)} V _{CE} =-2V, I _C =-1A			-1.1	V
Transition frequency	f _T	V _{CE} =-5V, I _C =-100mA , 100 f =100MHz			MHz
Collector Output Capacitance	Cob	f=1MHz		15	pF

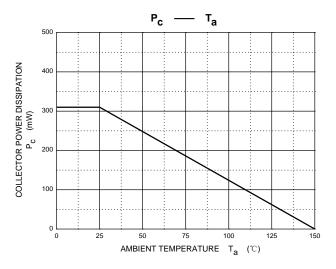


Typical Characteristics

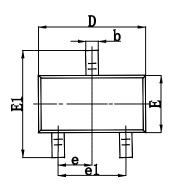


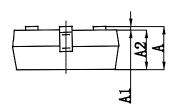


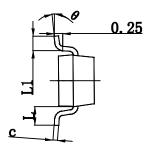




SOT-23 Package Outline Dimensions







Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Ш	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079	
Ш	0.550 REF		0.022 REF		
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	



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